



The TED1X is a compact and low-power MEMS gas sensor with ASIC for indoor air quality

The TED1X is metallic oxide semi-conductor type MEMS gas sensor for monitoring indoor air quality. It is a smallest, high sensitivity and ultra-low power multi-gas sensor with ASIC. Containing pre-installed software and specific algorithms is designed for detecting multi-gas and ambient temperature compensation. This sensor is consisted of nano-particle metal oxide sensing layer, micro heater, micro thickness membrane and Read-out IC. Those technologies provide high sensitivity, low-power consumption, fast response, small size and long-term stability. TED110 is a multi-gas sensor for monitoring Carbon monoxide(CO), combustible gases and a volatile organic compounds(VOCs), and also can be used as an equivalent carbon dioxide(eCO₂) sensor. Humans are the source of VOCs, therefore the CO₂ concentration trend follows VOCs trend. That's why TED110 can detect eCO₂.

Advantages

Small SMP packaging (**3 x 3 x 1mm**) with ROIC Self-Temperature compensation Long-term stability High sensitivity Fast response time Reasonable price Low power consumption

Applications

Air pollution monitoring Mobile smart device (phones, tablets, watches. etc) Air quality monitoring (indoor, vehicle, parking, IoT etc.) Ventilation (house, class room, industry and office etc.) Gas leak detection Breath checker Air conditioner, Hood, Air cleaner, Boiler Early fire detection











Technical Details of Gas Sensor

Target gas : VOCs, CO, EtOH, CH₄, NO₂, Toluene, H₂S etc Sensitivity (Rair/Rgas, 20ppm) CO: 250%, EtOH: 2000%, CH₄: 120%, Toluene: 800%, **Detecting Range** Carbon Monoxide (CO): 1~1000ppm Ethanol(C_2H_6OH ; EtOH): 1~1000ppm Methane (CH₄): 1~1000ppm Toluene ($C_6H_5CH_3$): 1~1000ppm Response time : 10sec

Die dimension: 0.55 x 0.55 x 0.3mm

Package dimension: 3 x 3 x 1mm³

Output: I2C Digital Output

Sensitivity for Each Gas

Sensitivity is defined as the sensor's I2C output counts at 50%RH humidity and 25°C ambient temperature. The following chart shows the sensitivity to VOCs in the best power mode of each gas.



Gas Concentration(ppm)

Electrical Characteristics

Parameter	Condition	Min	Тур	Max	Units
Supply Voltage			3.3		V
Maximum heater voltage(V_H)				1.3	V
Compensated ambient operating temperature		0		60	°C
Ambient operating humidity	Non-condensing	15		85	%RH
Storage temperature range		-40		125	°C
Average power consumption	10% duty cycle		3.9		mW
Peak power consumption			54		mW
Heater resistance	V _H =1V, 50%RH	51	60	69	Ω

WISE Control Gas Sensor

Datasheet for TED Series

Sensor resistance in clean air	V _H =1V, 50%RH	10		1000	kΩ
Life time	V _H =1V		>5		years

Package Outline Dimensions

The package is compatible with SMD assembly process. This package should be protected by water. If you need a water proof package then we can supply a special package with membrane filter (option).



Pin Assignment

TED110 has 10 pins and it's description is as following table.





Pin Number	Name	Description	Input Voltage Min (V)	Input Voltage Max (V)
1	VDD	Analog power supply voltage	3	3.6
2	GND	Analog power supply ground	0	
3	S_DATA	I ₂ C Data Line	-	3.3
4	S_CLK	I ₂ C Clock Line	-	3.3
5	OTP_VPP	OTP driving power	3.3	
6	RESET	ROIC reset pin	0 or 3.3	
7	ADD3	Sensor address setting pin	nsor address setting pin 0 or 3.3	
8	ADD4	Sensor address setting pin 0 or 3		3.3
9	ADD5	Sensor address setting pin	0 or 3.3	
10	ADD6	Sensor address setting pin	0 or 3.3	

Pin Function Description

Pin No.	Mnemonic	Function
1	VDD	ROIC Driving Power
		Input 3.3 V
2	GND	Common Ground
		VDD GND, I2C GND, OTP GND, RESET GND, ADDx GND
3	S_DATA	Data Line of I2C Communication
4	S_CLK	Clock Line of I2C Communication
5	OTP_VPP	OTP Driving Power
		ROIC Calibration Data is stored in OTP
6	RESET	ROIC Hardware Reset Pin
		Reset at 0V
7	ADD3	Address Setting Pin
		I2C Address ($0x1x \sim 0xFx$) can be set by power input control to ADD3 ~ 6 Pin
		Input 0 V : Low signal
		Input 3.3 V : High signal
		Address MSB Pin : ADD3
		Address LSB Pin : ADD6
8	ADD4	Same as ADD3
9	ADD5	Same as ADD3
10	ADD6	Same as ADD3



Circuit Component

Reference Diagram



ROIC Pin Assign				
Component Value Remarks				
R1	10ΚΩ	Pull-up resistor for RESET		
R2	10ΚΩ	Pull-up resistor for ADDRESS 3		
R3	10ΚΩ	Pull-up resistor for ADDRESS 4		
R4	10KΩ	Pull-up resistor for ADDRESS 5		
R5	10ΚΩ	Pull-up resistor for ADDRESS 6		

I2C Communication

According to the concept in IoT, ROIC provides I2C interface.

Address Setting At I2C ADD Part

7	6	5	4	3	2	1	0
I2C_ADD6	I2C_ADD5	I2C_ADD4	I2C_ADD3	0	0	0	R/W

Configuring Addresses on the I2C Protocol

I2C Address Setting

- ROIC supports I2C Communication
- To access ROIC set in circuit, you need to set address on I2C Protocol
- Unlike general I2C address configuration, Bit 1 ~ 3 are not used
- Bit 0 is set according to Read / Write purpose as in I2C standard
 - 0 : Write signal
 - 1 : Read signal

I2C Write Protocol



- I2C address transfer for write purposes
- ACK check
- Data transmission
 - 1st Data: Call Start Register Address
 - 2nd Data: Data to be stored in the register located consecutively starting from the
 - corresponding register address



- Transmission of stop signal after completion of transmission





ROIC Register

ROIC has a register which is a data storage space.

ROIC Register Map

Regi	ster	OTP					
Add	ress	Address	Read/	Namo	Description		
MSB	LSB	MSB LSB	Write	Name	Description		
5	6	56	RW	ANALOG_CNTL_0	FREQ<1:0> FREQ_DSP EN_OSC		
69	68	-	RW	PWM_DATA	PWM Width = PWM_DATA / 32, 1 period = 1 second / 250kHz * 1024 cycle = 4ms		
71	70	-	R	TEMPERATURE_OUTPUT	TEMPERATURE(°C) = TEMPERATURE_OUTPUT / 256		
73	72	-	R	GAS_OUTPUT	GAS DENSITY(ppm) = GAS_OUTPUT / 256		
75	74	-	R	IR_OUTPUT	$IR(^{\circ}C) = IR_OUTPUT / 128$		
7	6	-	R	STATUS	EN_IR EN_GAS EN_TEMP PEN OTP_RD OTP_WR PROG PTM		
7	6	-	W	COMMAND	0 : initialize ROIC (OTP to Register) 1 : restart ROIC 6 : write data to OTP 7 : read data from OTP 8 : stop ROIC		

ROIC Register Map

Register Map Description

- There are two kinds of storage devices in ROIC

— OTP

Calibration data is stored

Write once (impossible to write after)

- Similar to ROM (Read Only Memory)
- Nonvolatile Data

— Register

Storage space of ROIC internal calculation result

Initialization to copy OTP data to Register after inputting drive voltage to VDD

Similar to RAM (Random Access Memory)

Volatile Data

- Each register size is 8 bits (1 byte)

Register	Function	Description
Register 56 FREQ AFE Clock selection		AFE Clock selection
		2 bit configuration
Requires 0x08 setting at ROIC		Requires 0x08 setting at ROIC Initialization
		(see. ROIC Initialize Sequence)
	FREQ DSP	Digital Signal Process Clock selection

Register Function Description



		1 bit configuration
		Requires high setting at ROIC Initialization
	EN_OSC	Internal VCO enable
		1 bit configuration
		Requires high setting at ROIC Initialization
Register 68, 69	PWM Output	Used to keep the gas sensor at room
		temperature
		2 bytes
		16 bit Signed Integer used but negative is
		excluded. (0 ~ 32767)
Register 70, 71	Temperature Output	Temperature Sensor Output
		2 bytes
		16 bit Signed Integer (-32768 ~ 32767) / 256
		= Current temperature (°C)
		R available (W not available)
Register 72, 73	Gas Output	Gas Sensor Output
		2 bytes
		16 bit Unsigned Integer (0 ~ 65535)
		R available (W not available)
Register 74, 75	IR Output	IR Sensor Output (Not supported)
		2 bytes
		16 bit Unsigned Integer (0 ~ 65535)
		R available (W not available)
Register 76	Write(Read)	cmd 0 : Copy OTP Data to Register
		cmd 1 : Restart ROIC
		cmd 6 : OTP Write Command
		cmd 7 : OTP Read Command
		cmd 8 : Stop ROIC



ROIC Initialize

Initialization is required to use ROIC after driving power input Write the following data in the Register described below (Register No. 56, 76)

ROIC Initialize Sequence

Sequence No.	Register No.(Hex)	Register Data Hex Value	Function Hex Value
1	56 (0x38)	0x0B	PREQ (AFE Clock selection) : 0x08 1 0 PREQ_DSP (DSP Clock selection) : 0x02 1 1 EN_OSC (Internal VCO enable) : 0x01 1 1
2	76 (0x4C)	0x00 0 0 0 0 0 0 0 0 0	Cmd 0 : 0x00 0 0 0 0 0 0